

PROCEEDINGS OF SPIE

Quantum Dots and Nanostructures: Growth, Characterization, and Modeling XIII

**Diana L. Huffaker
Holger Eisele
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Editors

**15–16 February 2016
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 9758

Proceedings of SPIE 0277-786X, V. 9758

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Quantum Dots and Nanostructures: Growth, Characterization, and Modeling XIII, edited by Diana L. Huffaker, Holger Eisele, Kimberly A. Dick, Proc. of SPIE Vol. 9758, 975801 · © 2016 SPIE
CCC code: 0277-786X/16/\$18 · doi: 10.1117/12.2240433

Proc. of SPIE Vol. 9758 975801-1

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Author(s), "Title of Paper," in *Quantum Dots and Nanostructures: Growth, Characterization, and Modeling XIII*, edited by Diana L. Huffaker, Holger Eisele, Kimberly A. Dick, Proceedings of SPIE Vol. 9758 (SPIE, Bellingham, WA, 2016) Six-digit Article CID Number.

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781628419931

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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Contents

- v *Authors*
vii *Conference Committee*

SESSION 1 InAs QUANTUM DOTS

- 9758 02 **A detailed investigation of strain patterning effect on bilayer InAs/GaAs quantum dot with varying GaAs barrier thickness (Invited Paper) [9758-1]**
9758 03 **InAs/GaAs quantum-dot light emitters monolithically grown on Si substrate [9758-2]**

SESSION 2 LARGE QUANTUM DOTS

- 9758 09 **Analysing radiative and non-radiative recombination in InAs QDs on Si for integrated laser applications [9758-8]**

SESSION 3 PHOTONICS APPLICATIONS AND NANOWIRES

- 9758 0B **Surface-plasmon-enhanced photoluminescence of quantum dots based on open-ring nanostructure array [9758-10]**
9758 0E **Growth of high-quality self-catalyzed core-shell GaAsP nanowires on Si substrates [9758-13]**

SESSION 4 NANOPARTICLES

- 9758 0G **Enhanced absorption with quantum dots, metal nanoparticles, and 2D materials (Invited Paper) [9758-15]**

SESSION 5 NANOMATERIALS

- 9758 0J **Plasmonically enhanced photoluminescence of nanoscale semiconductors [9758-22]**
9758 0L **Characterisation of high current density resonant tunneling diodes for THz emission using photoluminescence spectroscopy [9758-24]**

POSTER SESSION

- 9758 0M **Crystalline phase destruction in silicon films by applied external electrical field and detected by using the laser spectroscopy [9758-25]**

- 9758 ON **Structural characteristics of Au-GaAs nanostructures for increased plasmonic optical enhancement** [9758-26]
- 9758 OO **Magneto-optic evaluation of antiferromagnetic α -Fe₂O₃ nanoparticles coated on a quartz substrate** [9758-27]
- 9758 OQ **Effect of varying capping composition and number of strain-coupled stacks on In_{0.5}Ga_{0.5}As quantum dot infrared photodetectors** [9758-29]
- 9758 OR **Photoluminescence blinking and spectral diffusion of single CdSe/ZnS nanocrystals: charge fluctuation effects** [9758-30]
- 9758 OS **Growth strategy to achieve mono-modal quantum dot size distribution in InAs/GaAs multi stack coupled heterostructures** [9758-31]
- 9758 OT **Diffusion impact on thermal stability in self-assembled bilayer InAs/GaAs quantum dots (QDs)** [9758-32]

Authors

Numbers in the index correspond to the last two digits of the six-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first four digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Aagesen, Martin, 0E
Abbey, Grant P., 0N
Abraham, Gabrielle, 0J
Ahmad, Aijaz, 0S
Baba, Razvan, 0L
Bajwa, Pooja, 0J
Balasubramanian, Srinath, 0O
Balgarkashi, Akshay, 0Q, 0S
Beanland, Richard, 09, 0E
Chakrabarti, Subhananda, 02, 0Q, 0S, 0T
Chan, Yin Thai, 0G
Chen, S., 03
Cheng, Li-Jing, 0B
Churchill, Hugh, 0J
Das, Debabrata, 0T
Ghadi, Hemant, 0Q
Guchhait, Asim, 0G
Herzog, Joseph B., 0J, 0N
Heyes, Collin, 0J
Hogg, Richard A., 0L
Huo, Suguo, 0E
Ibuki, Hiroto, 0R
Ihara, Toshiyuki, 0R
Jacobs, Kristof J. P., 0L
Jiang, Q., 03
Jurczak, Pamela, 0E
Kale, Bharat B., 0O
Kanemitsu, Yoshihiko, 0R
Kannegulla, Akash, 0B
Kim, Dongyoung, 0E
Kumar, Ganapathy, 0O
Liao, M., 03
Liu, Huiyun, 03, 09, 0E
Liu, Ye, 0B
Mahajan, Satish M., 0O
Manasreh, Omar, 0N
Milovzorov, D. E., 0M
Mowbray, David J., 09
Mukai, Toshikazu, 0L
Mukherjee, Bablu, 0G
Nusir, Ahmad I., 0N
Ohnishi, Dai, 0L
Orchard, Jonathan R., 09
Panda, Debiprasad, 02, 0Q, 0S, 0T
Panmand, Rajendra, 0O
Sanchez, Ana M., 0E
Seeds, A., 03
Sehara, Navneet, 02, 0Q, 0T
Shetty, Saikalash, 0Q, 0S
Shutts, Samuel, 09
Simsek, Ergun, 0G
Singhal, Jashan, 02, 0T
Smowton, Peter M., 09
Sobiesierski, Angela, 09
Stevens, Benjamin J., 0L
Tang, M., 03
Tejerina, Alejandro, 0J
Tongbram, B., 02, 0T
Ward, Thomas, 0E
Woodhead, Chris, 09
Wu, Jiang, 03, 09, 0E
Young, Rob J., 09
Zhang, Yunyan, 0E

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Session Chairs

- 1 InAs Quantum Dots
Jonathan R. Orchard, The University of Sheffield (United Kingdom)
- 2 Large Quantum Dots
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